



### US2JDF

#### Product Summary (@T<sub>A</sub> = +25°C)

V <sub>RRM</sub> (V)	I <sub>0</sub> (A)	V <sub>F</sub> (MAX) (V)	Ι <sub>R(MAX)</sub> (μΑ)
600	2	1.7	5

### **Description and Applications**

The US2JDF is a rectifier packaged in the low profile D-FLAT package. Providing ultra-fast recovery time for high efficiency, this device is ideal for use in general rectification applications such as:

- Switching Mode Power Supplies
- DC-DC Converters

#### 2.0A SURFACE MOUNT ULTRA-FAST RECTIFIER

#### **Features and Benefits**

- Glass Passivated Die Construction
- Ultra-Fast Recovery Time for High Efficiency
- Surge Overload Rating to 50A Peak
- High Current Capability
- Low Profile Design, Package Height less than 1.1mm
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Mechanical Data**

- Case: D-FLAT
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (€3)
- Polarity: Cathode Band
- Weight: 0.064 grams (Approximate)

D-FLAT



Top View

### Ordering Information (Note 4)

Case	Packaging
D-FLAT	10000/Tape & Reel
	D-FLAT

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

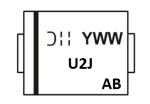
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**

Notes:



U2J= Product Type Marking Code Code D'' = Manufacturer's Code Marking YWW = Date Code Marking Y = Last Digit of Year (ex: 4 for 2014) WW = Week Code (01 to 53) AB = Foundry and Assembly Code



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

Characteristic		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage (Note 5)		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	600	V
RMS Reverse Voltage		V <sub>R(RMS)</sub>	420	V
Average Rectified Output Current	@ T <sub>T</sub> = +75°C	lo	2.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I <sub>FSM</sub>	50	А

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Terminal	R <sub>0JT</sub>	22	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

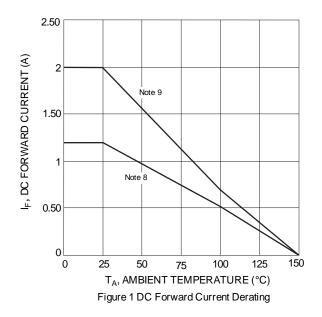
Characteristic		Symbol	Value	Unit
Minimum Reverse Breakdown Voltage (Note 5)	@I <sub>R</sub> = 5µA	V <sub>(BR)R</sub>	600	V
Maximum Forward Voltage Drop @ I <sub>F</sub> = 1.0A		VF	1.7	V
Peak Reverse Current at Rated DC Blocking Voltage (Note 5)	@ T <sub>A</sub> = +25°C @ T <sub>A</sub> = +100°C		5.0 100	μA
Maximum Reverse Recovery Time (Note 6)		t <sub>rr</sub>	75	ns
Typical Total Capacitance (Note 7)		CT	10	pF

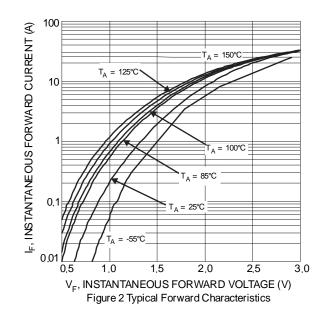
Notes: 5. Short duration pulse test used to minimize self-heating effect.

6. Measured with  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{rr} = 0.25A$ . See Figure 7.

7. Measured at f=1.0MHz and applied reverse voltage of 4.0V DC.

Bevice mounted on FR-4 substrate, 1in.\*1in., 2oz, single-sided, PC boards with 0.1in.\*0.15in. copper pads.
Device mounted on FR-4 substrate, 0.4in.\*0.5in., 2oz, single-sided, PC boards with 0.2in.\*0.25in. copper pads.







## **US2JDF**

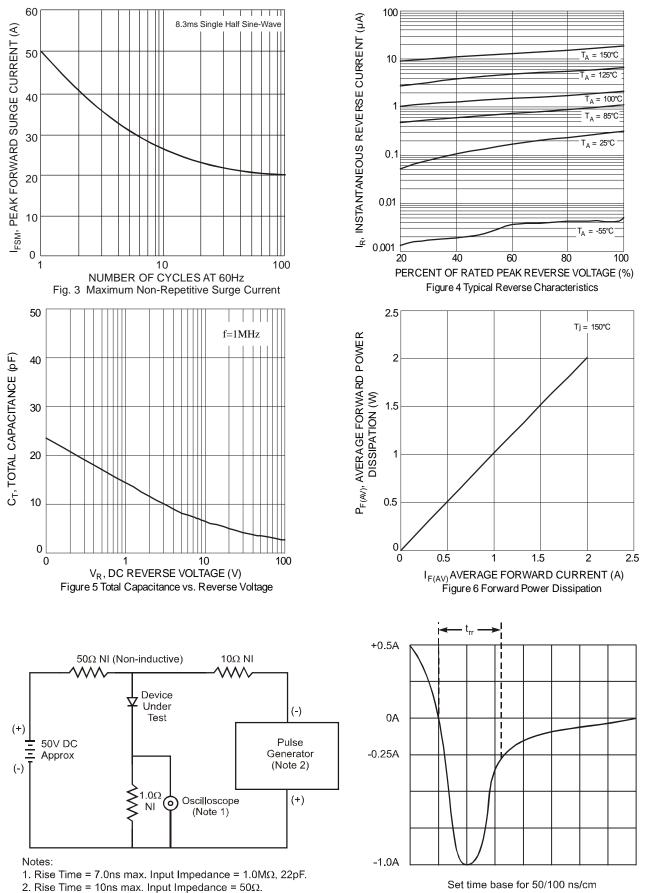


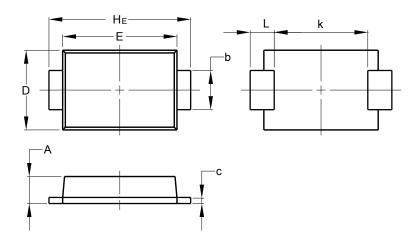
Fig. 7 Reverse Recovery Time Characteristic and Test Circuit

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# Package Outline Dimensions

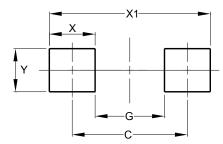
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



D-FLAT				
Dim	Min	Max		
Α	0.90	1.10		
b	1.25	1.65		
c	0.10	0.40		
D	2.25	2.95		
Е	3.95	4.60		
k	2.80	-		
H₌	5.00	5.60		
L	0.50	1.30		
All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	4.65
G	2.80
Х	1.85
X1	6.50
Y	1.70



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